

## **Unraveling the crucial role of Cu(I) intermediates in self-reducing MOD inks for flexible electronics**

W. Marchal,<sup>a</sup> A. Longo,<sup>b</sup> V. Briois,<sup>c</sup> K. Van Hecke,<sup>d</sup> F. Mattelaer,<sup>e</sup> K. Elen,<sup>a</sup> M.K. Van Bael,<sup>a</sup> A. Hardy<sup>a,\*</sup>

<sup>a</sup> UHasselt - Hasselt University, Institute for Materials Research (IMO-IMOMEC), Inorganic and Physical chemistry, Agoralaan D, 3590 Diepenbeek, Belgium

<sup>b</sup> ESRF – European Synchrotron Radiation Facility, Avenue des martyrs 71, 38043 Grenoble, Cedex 9, France

<sup>c</sup> Synchrotron SOLEIL, L'orme des merisiers, Saint-Aubin, 91112 Gif-sur Yvette, France

<sup>d</sup> Ghent University, Department of Inorganic and Physical Chemistry, Krijgslaan 281 S3, 9000 Gent, Belgium

<sup>e</sup> Ghent University, Department of Solid State Sciences, Krijgslaan 281 S1, 9000 Gent, Belgium

\*An.Hardy@uhasselt.be

The integration of electronic components in flexible materials such as paper, textiles and plastics is identified as a key challenge for the development of future smart applications including sensors, wireless communication and wearables. In this perspective, the fast and scalable low-temperature deposition of nanoscale metallic features is of utmost importance. Recently, a new class of copper inks, consisting out of self-reducing amine-based formate complexes was developed.<sup>1,2</sup> These novel inks yield metallic depositions with an outstanding electrical conductivity ( $\pm 10 \mu\Omega \text{ cm}$ ) at temperatures of 150 °C or less, well below the reduction temperature of neat copper formate (around 225 °C). However, a fundamental explanation for this reaction mechanism and the corresponding temperature shift upon coordination is currently missing. In this work, a wide variety of self-reducing copper complex inks were synthesized and analyzed in detail using single-crystal XRD, EXAFS, FTIR and Raman spectroscopy. In addition, the reduction mechanism was monitored using in-situ XRD and XANES, in combination with cutting-edge statistical data treatment methods such as principal component analysis (PCA), revealing the crucial role of the Cu(I) intermediate and its complex structure.<sup>3</sup> Eventually, recommendations for the design of effective inks can be formulated, contributing to a future of flexible printed electronics.

The authors would like to acknowledge the SIM - Met@link project for financial support.

1 A.Yabuki, S. Tanaka, *Materials Research Bulletin*, **2012**, *47*, 4107.

2 Y. Farraj, M. Grouchko, S. Magdassi, *Chemical Communications*, **2015**, *51*, 1578.

3 W.Marchal, PhD thesis, **2018**.